

N-channel 40 V, 1.4 mΩ standard level MOSFET in LFPAK56E 8 August 2023 Product data sheet

1. General description

Automotive qualified N-channel MOSFET using the latest Trench 9 low ohmic superjunction technology, housed in an enhanced LFPAK56E package. This product has been fully designed and qualified to meet AEC-Q101 requirements delivering high performance and endurance.

2. Features and benefits

- Fully automotive qualified to AEC-Q101:
 - 175 °C rating suitable for thermally demanding environments
- Trench 9 Superjunction technology:
 - Reduced cell pitch enables enhanced power density and efficiency with lower R_{DSon} in same footprint
 - Improved SOA and avalanche capability compared to standard TrenchMOS
 - Tight V_{GS(th)} limits enable easy paralleling of MOSFETs
- LFPAK Gull Wing leads:
 - High Board Level Reliability absorbing mechanical stress during thermal cycling, unlike traditional QFN packages
 - Visual (AOI) soldering inspection, no need for expensive x-ray equipment
 - Easy solder wetting for good mechanical solder joint
- LFPAK copper clip technology:
 - Improved reliability, with reduced R_{th} and R_{DSon}
 - Increases maximum current capability and improved current spreading

3. Applications

- 12 V automotive systems
- Motors, lamps and solenoid control
- Start-Stop micro-hybrid applications
- Transmission control
- Ultra high performance power switching

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-------------------|----------------------------------|---|-----|------|------|-----|------|
| V _{DS} | drain-source voltage | 25 °C ≤ T _j ≤ 175 °C | | - | - | 40 | V |
| I _D | drain current | V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u> | [1] | - | - | 190 | Α |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; <u>Fig. 1</u> | | - | - | 395 | W |
| Static chara | cteristics | | | | | - | |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11 | | 0.74 | 1.06 | 1.4 | mΩ |

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------|-------------------|--|-----|-----|-----|------|
| Dynamic cl | haracteristics | · · · · · | | | _ | |
| Q _{GD} | gate-drain charge | I _D = 25 A; V _{DS} = 32 V; V _{GS} = 10 V; Fig. 13; Fig. 14 | - | 13 | 27 | nC |
| Source-dra | ain diode | · · · | | | | |
| Qr | recovered charge | I_{S} = 25 A; dI _S /dt = -100 A/µs; V _{GS} = 0 V; V _{DS} = 20 V | - | 39 | - | nC |
| S | softness factor | $I_{S} = 25 \text{ A}; \text{ d}_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V}; \\ \text{V}_{DS} = 20 \text{ V}; \text{ T}_{j} = 25 ^{\circ}\text{C}$ | - | 0.7 | - | |

[1] 190A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|-----------------------------------|----------------|
| 1 | S | source | | |
| 2 | S | source | | |
| 3 | S | source | | D |
| 4 | G | gate | | |
| mb | D | mounting base; connected to drain | | G mbb076 S |
| | | | LFPAK56E; Power- SO8 (SOT1023) | |

6. Ordering information

| T | ~ | 0.1.1 | |
|----------|----|----------|-------------|
| lable | 3. | Ordering | information |

| Type number | Package | | | | |
|-------------------|------------------------|--|---------|--|--|
| | Name | Description | Version | | |
| BUK7J1R4-40H | LFPAK56E; Power-SO8 | plastic, single-ended surface-mounted package (LFPAK56); 4 leads; 1.27 mm pitch | SOT1023 | | |
| BUK7J1R4-40H/A002 | LFPAK56E; Power-SO8 | plastic, single-ended surface-mounted package (LFPAK56); 4 leads; 1.27 mm pitch | SOT1023 | | |

7. Marking

| Table 4. Marking codes | | | | | |
|------------------------|--------------|--|--|--|--|
| Type number | Marking code | | | | |
| BUK7J1R4-40H | 71H440E | | | | |
| BUK7J1R4-40H/A002 | 71H440E | | | | |

BUK7J1R4-40H

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

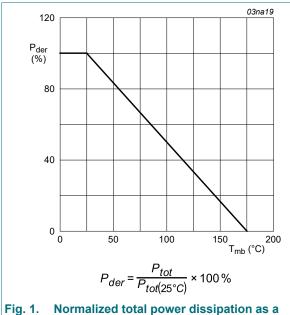
| Symbol | Parameter | Conditions | | Min | Мах | Unit |
|----------------------|--|--|---------|-----|-----|------|
| V _{DS} | drain-source voltage | 25 °C ≤ T _j ≤ 175 °C | | - | 40 | V |
| V _{GS} | gate-source voltage | DC; T _j ≤ 175 °C | | -10 | 20 | V |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; <u>Fig. 1</u> | | - | 395 | W |
| ID | drain current | V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u> | [1] | - | 190 | Α |
| | | V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u> | [1] | - | 190 | А |
| I _{DM} | peak drain current | pulsed; t _p ≤ 10 µs; T _{mb} = 25 °C; <u>Fig. 3</u> | | - | 600 | А |
| T _{stg} | storage temperature | | | -55 | 175 | °C |
| Tj | junction temperature | | | -55 | 175 | °C |
| Source-drai | n diode | - | | | | |
| I _S | source current | T _{mb} = 25 °C | [2] | - | 145 | А |
| I _{SM} | peak source current | pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$ | | - | 600 | А |
| Avalanche r | ruggedness | 1 | | | | |
| E _{DS(AL)S} | non-repetitive drain- source avalanche energy | $\label{eq:ID} \begin{array}{l} I_D = 190 \text{ A}; V_{sup} \leq 40 \text{ V}; \text{R}_{GS} = 50 \Omega; \\ V_{GS} = 10 \text{ V}; \text{T}_{j(\text{init})} = 25 ^\circ\text{C}; \text{ unclamped}; \\ \hline \text{Fig. 4} \end{array}$ | [3] [4] | - | 154 | mJ |

[1] 190A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

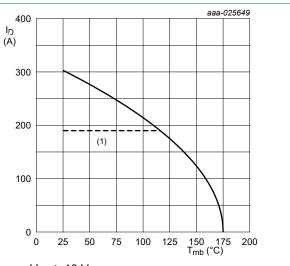
[2] 145A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[3] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[4] Refer to application note AN10273 for further information.



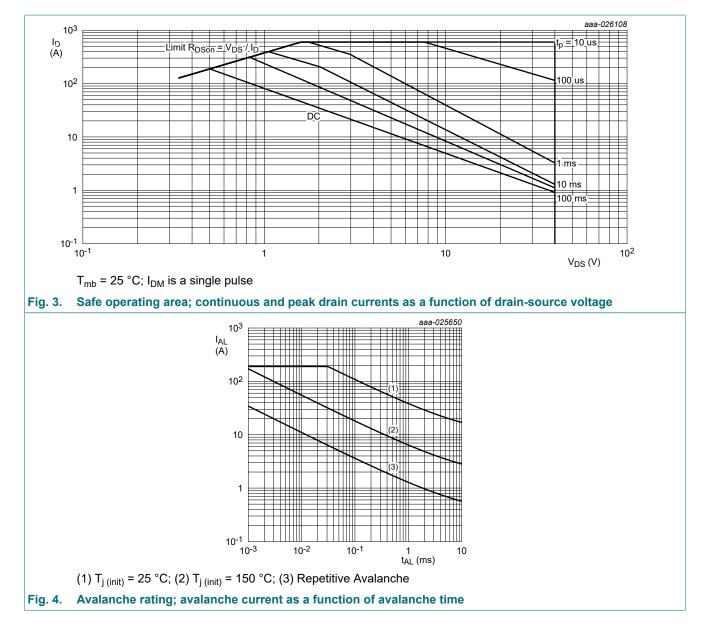




V_{GS} ≥ 10 V

(1) 190A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

Fig. 2. Continuous drain current as a function of mounting base temperature

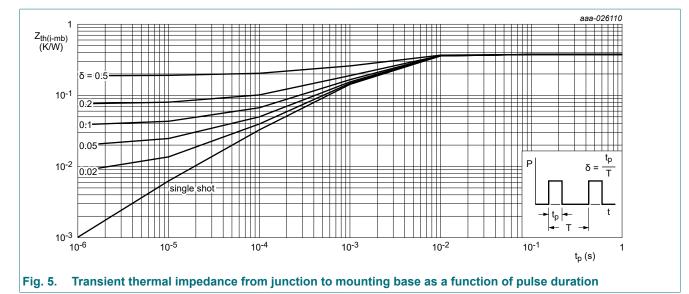


9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------|---|---------------|-----|------|------|------|
| | thermal resistance from junction to mounting base | <u>Fig. 5</u> | - | 0.29 | 0.38 | K/W |

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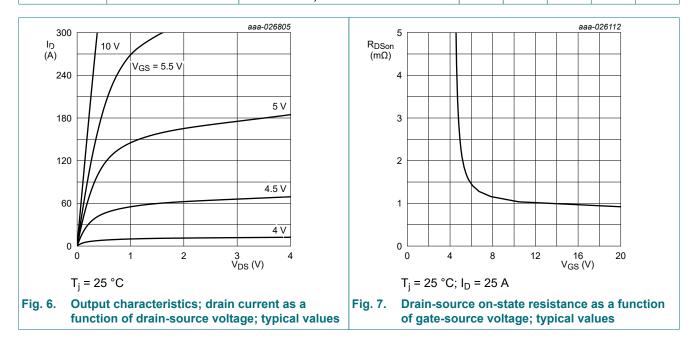


10. Characteristics

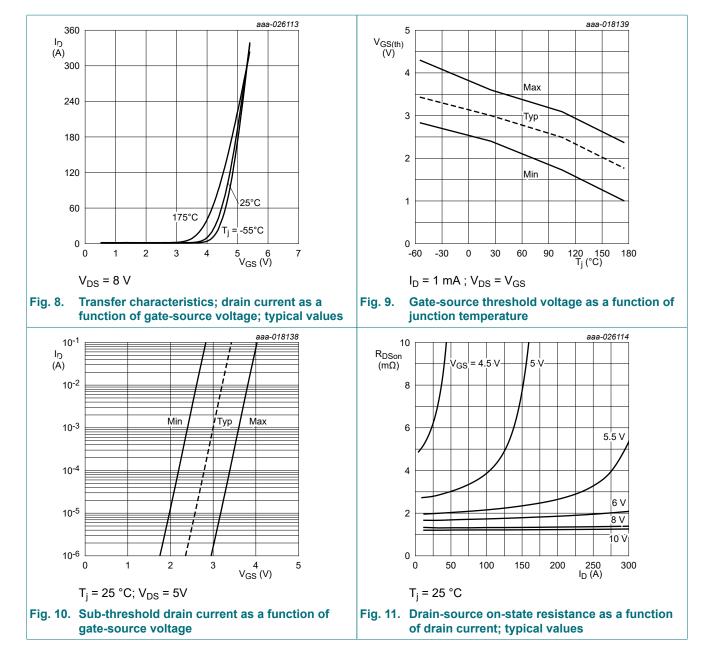
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|-------------------------------------|--|------|------|------|------|
| Static chara | cteristics | | | | | |
| V _{(BR)DSS} | drain-source | I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C | 40 | 42 | - | V |
| | breakdown voltage | I _D = 250 μA; V _{GS} = 0 V; T _j = -40 °C | - | 39.6 | - | V |
| | | I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C | 36 | 38.9 | - | V |
| V _{GS(th)} | gate-source threshold voltage | $I_D = 1 \text{ mA}; V_{DS}=V_{GS}; T_j = 25 \text{ °C}; Fig. 9;$ Fig. 10 | 2.4 | 3 | 3.6 | V |
| | | I _D = 1 mA; V _{DS} =V _{GS} ; T _j = -55 °C; <u>Fig. 9</u> | - | - | 4.3 | V |
| | | I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 175 °C; <u>Fig. 9</u> | 1 | - | - | V |
| I _{DSS} | drain leakage current | V _{DS} = 40 V; V _{GS} = 0 V; T _j = 25 °C | - | 0.1 | 1 | μA |
| | | V _{DS} = 16 V; V _{GS} = 0 V; T _j = 125 °C | - | 2.4 | 10 | μA |
| | | V _{DS} = 40 V; V _{GS} = 0 V; T _j = 175 °C | - | 240 | 500 | μA |
| I _{GSS} | gate leakage current | V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C | - | 2 | 100 | nA |
| | | V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C | - | 2 | 100 | nA |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; <u>Fig. 11</u> | 0.74 | 1.06 | 1.4 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _j = 105 °C; Fig. 12 | 1.05 | 1.57 | 2.23 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _j = 125 °C; Fig. 12 | 1.16 | 1.74 | 2.45 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 12 | 1.46 | 2.18 | 3.05 | mΩ |
| R _G | gate resistance | f = 1 MHz; T _j = 25 °C | 0.4 | 1 | 2.5 | Ω |
| Dynamic ch | aracteristics | | 1 | | | |
| Q _{G(tot)} | total gate charge | I _D = 25 A; V _{DS} = 32 V; V _{GS} = 10 V; | - | 73 | 103 | nC |
| Q _{GS} | gate-source charge | Fig. 13; Fig. 14 | - | 21 | 32 | nC |
| Q _{GD} | gate-drain charge | 1 | - | 13 | 27 | nC |

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| Symbol | Parameter | Conditions | Mi | ו Typ | Max | Unit |
|---------------------|------------------------------|--|----|-------|------|------|
| C _{iss} | input capacitance | V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz; | - | 5436 | 7610 | pF |
| C _{oss} | output capacitance | T _j = 25 °C; <u>Fig. 15</u> | - | 1314 | 1840 | pF |
| C _{rss} | reverse transfer capacitance | | - | 238 | 524 | pF |
| t _{d(on)} | turn-on delay time | V_{DS} = 30 V; R _L = 1.2 Ω; V _{GS} = 10 V; R _{G(ext)} = 5 Ω | - | 19 | - | ns |
| t _r | rise time | | - | 17 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 43 | - | ns |
| t _f | fall time | | - | 21 | - | ns |
| Source-dra | ain diode | | | | | |
| V _{SD} | source-drain voltage | I_{S} = 25 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 16</u> | - | 0.8 | 1.2 | V |
| t _{rr} | reverse recovery time | I_{S} = 25 A; dI _S /dt = -100 A/µs; V _{GS} = 0 V; | - | 37 | - | ns |
| Q _r | recovered charge | V _{DS} = 20 V | - | 39 | - | nC |
| S | softness factor | $ I_{S} = 25 \text{ A}; dI_{S}/dt = -100 \text{ A}/\mu s; V_{GS} = 0 \text{ V}; \\ V_{DS} = 20 \text{ V}; T_{j} = 25 ^{\circ}\text{C} $ | - | 0.7 | - | |
| | | I_{S} = 25 A; dI _S /dt = -500 A/µs; V _{GS} = 0 V; V _{DS} = 20 V; T _j = 25 °C | - | 0.56 | - | |

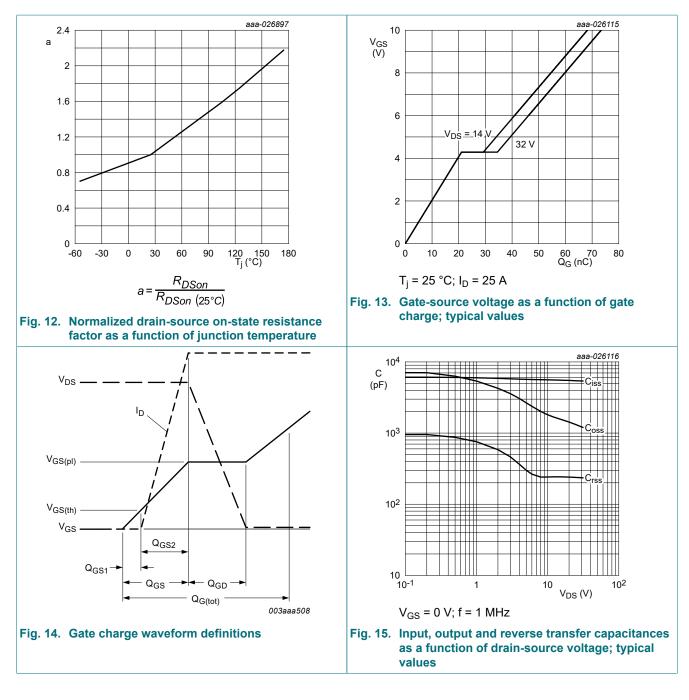


Product data sheet



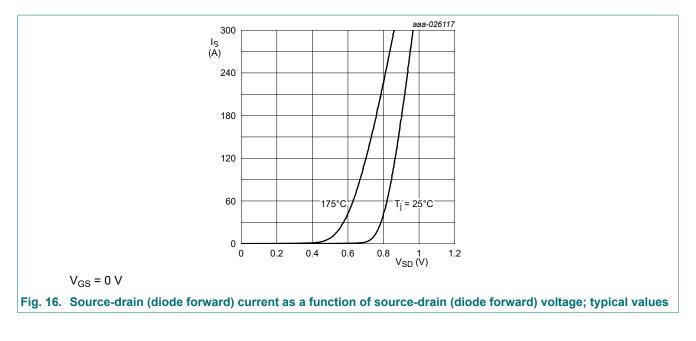
Product data sheet

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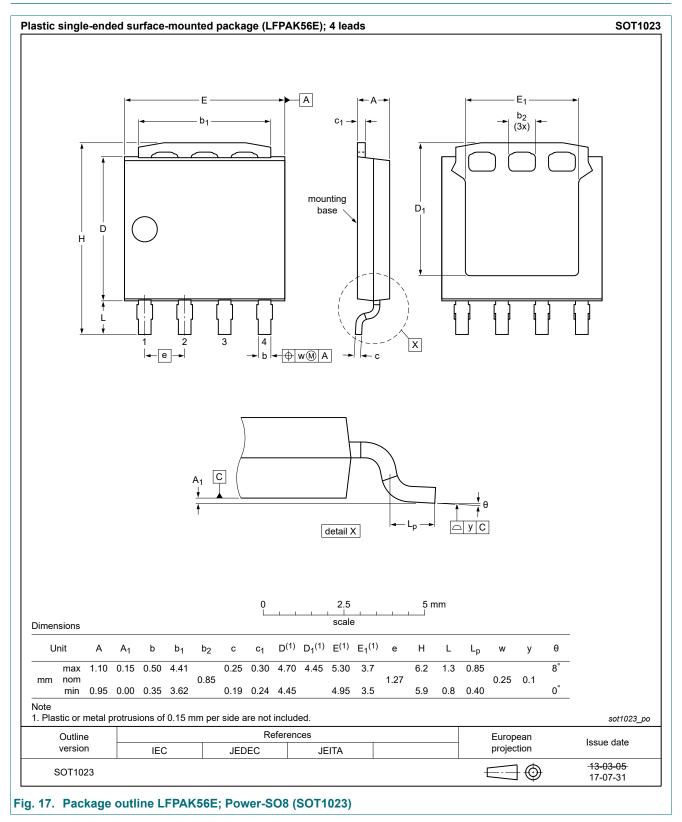
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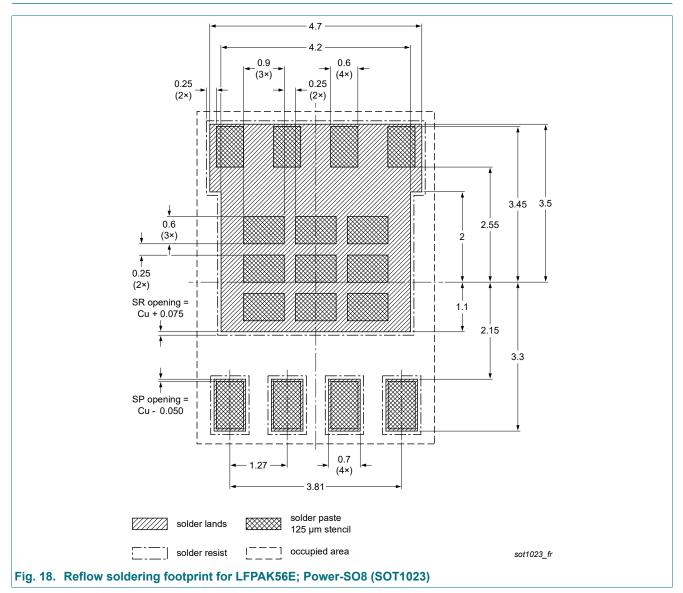


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11. Package outline



12. Soldering



13. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|-----------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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